

# PESDWC2XD5VBL

# **Bi-directional 5V Low Capacitance ESD Protector**

#### Description

The PESDWC2XD5VBL protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.



#### DFN0603-2L(Bottom View)

#### Feature

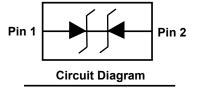
- 35W peak pulse power per line (t<sub>P</sub> = 8/20µs)
- DFN0603-2L package
- Replacement for MLV(0201)
- > Bidirectional configurations
- Response time is typically < 1ns</p>
- High ESD protection
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) ±12KV(air), ±10KV(contact);
  IEC 61000-4-4 (EFT) 40A (5/50ns)

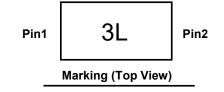
#### **Applications**

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies

#### **Mechanical Characteristics**

- Mounting position: Any
- Qualified max reflow temperature:260°C
- > Device meets MSL 1 requirements
- DFN0603-2L without plating





# **Electronics Parameter**

Symbol	Parameter		
VRWM	Peak Reverse Working Voltage		
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>		
VBR	Breakdown Voltage @ I⊤		
Iт	Test Current		
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P <sub>PP</sub>	Peak Pulse Power		
CJ	Junction Capacitance		
١F	Forward Current		
VF	Forward Voltage @ I <sub>F</sub>		

# 

# Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V <sub>RWM</sub>				5	V
Breakdown Voltage	V <sub>BR</sub>	It = 1mA	5.6	6.7	7.8	V
Reverse Leakage Current	IR	V <sub>RWM</sub> = 5V T=25°С			1.0	μA
Clamping Voltage	Vcl	I <sub>PP</sub> =16A t <sub>p</sub> =100ns		15		V
Clamping Voltage	Vc	I <sub>PP</sub> =1A t <sub>P</sub> = 8/20µs		7	9	V
Clamping Voltage	Vc	I <sub>PP</sub> =3.5A t <sub>P</sub> = 8/20μs		11	12	V
Junction Capacitance	Cj	V <sub>R</sub> =0V f = 1MHz		3		pF

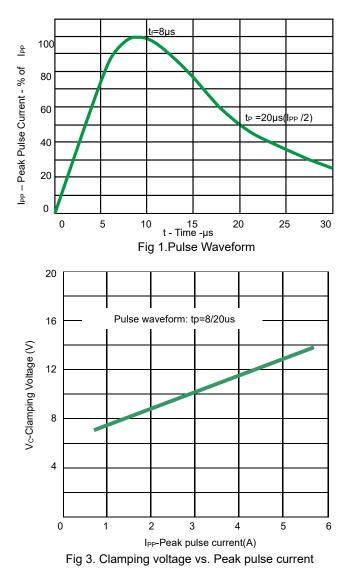
## Absolute maximum rating@25℃

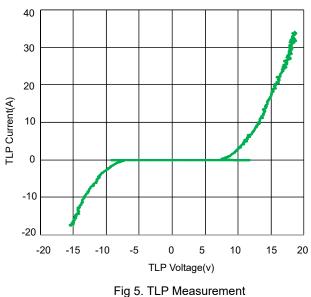
Rating	Symbol	Value	Units
Peak Pulse Power (t <sub>p</sub> =8/20µs)	P <sub>pp</sub>	35	W
Operating Temperature	TJ	-55 to 150	°C
Storage Temperature	Tstg	-55 to 150	°C

# PESDWC2XD5VBL

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#### **Typical Characteristics**





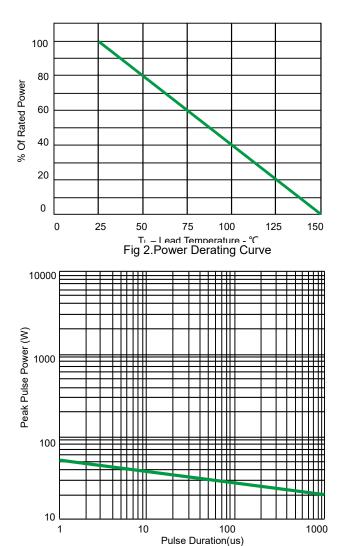
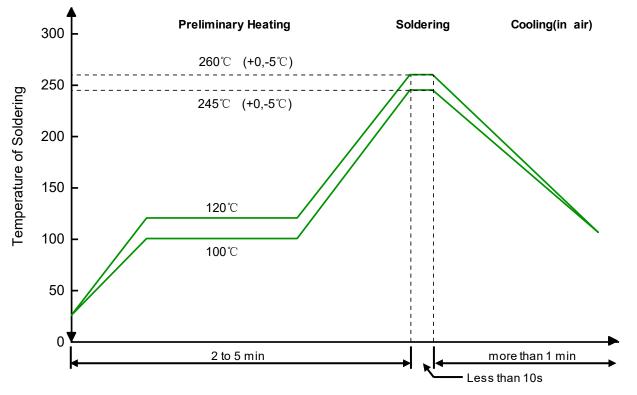


Fig 4. Non Repetitive Peak Pulse Power vs. Pulse time

#### PESDWC2XD5VBL

#### **Solder Reflow Recommendation**



Remark: Pb free for 260°C; Pb for 245°C.

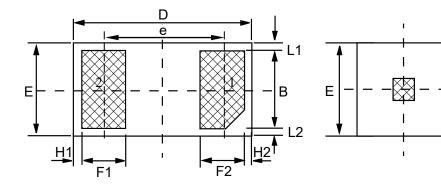
#### PCB Design

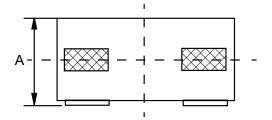
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

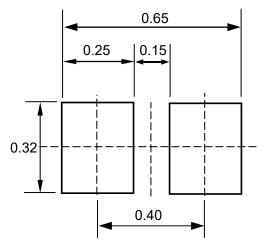
- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

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## Product dimension (DFN0603-2L)







Unit: mm

Suggested PCB Layout

Dim	Millimeters			
	MIN	Тур.	МАХ	
А	0.270	0.300	0.340	
В	0.200	0.250	0.300	
D	0.550	0.600	0.650	
E	0.250	0.300	0.350	
е	-	0.350	-	
F1	0.130	0.180	0.230	
F2	0.130	0.180	0.230	
L1	0.015	0.030	0.045	
L2	0.015	0.030	0.045	
H1	0.030	0.045	0.060	
H2	0.030	0.045	0.060	

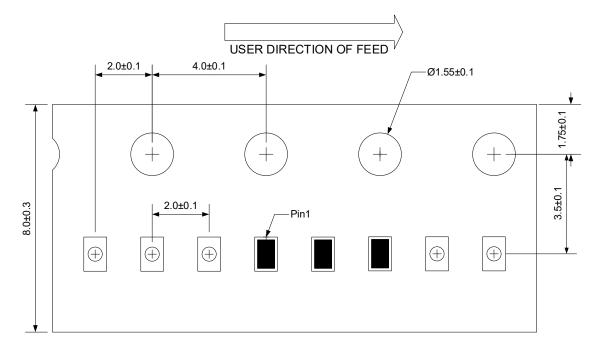
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# Ordering information

Device	Package	Reel	Shipping
PESDWC2XD5VBL	DFN0603-2L	7"	10000 / Tape & Reel

## PESDWC2XD5VBL

#### Load with information



Unit:mm

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